MCD44-12io8B

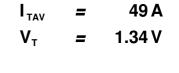
= 2x 1200 V

Thyristor \ Diode Module

Phase leg

Part number

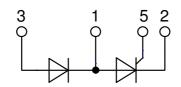
MCD44-12io8B



 V_{RRM}



Backside: isolated **E**72873



Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability
- Direct Copper Bonded Al2O3-ceramic

Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

Package: TO-240AA

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting

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- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

Terms Conditions of usage:

The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact your local sales office. Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact your local sales office. Should you intend to use the product in aviation, in health or life endangering or life support applications, please notify. For any such application we urgently recommend

to perform joint risk and quality assessments;
the conclusion of quality agreements;

- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures.

IXYS reserves the right to change limits, conditions and dimensions.

Data according to IEC 60747and per semiconductor unless otherwise specified

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MCD44-12io8B

Rectifier		• ····		1	Ratings		
Symbol	Definition	Conditions		min.	typ.	max.	Uni
V _{RSM/DSM}	max. non-repetitive reverse/forwa	5 5	$T_{VJ} = 25^{\circ}C$			1300	\
V _{RRM/DRM}	max. repetitive reverse/forward bl		$T_{vJ} = 25^{\circ}C$			1200	١
R/D	reverse current, drain current	V _{R/D} = 1200 V	$T_{vJ} = 25^{\circ}C$			100	μ/
		V _{R/D} = 1200 V	$T_{vJ} = 125^{\circ}C$			5	m/
V _T	forward voltage drop	$I_{T} = 100 \text{ A}$	$T_{vJ} = 25^{\circ}C$			1.34	١
		I _T = 200 A				1.75	١
		$I_{T} = 100 \text{ A}$	$T_{vJ} = 125^{\circ}C$			1.34	١
		I _T = 200 A				1.80	١
I _{tav}	average forward current	$T_c = 85^{\circ}C$	T _{vJ} = 125°C			49	1
I _{T(RMS)}	RMS forward current	180° sine				77	/
V _{T0}	threshold voltage		T _{v.i} = 125°C			0.85	١
r _τ	slope resistance } for power lo	oss calculation only	vo			5.3	mΩ
R _{thJC}	thermal resistance junction to cas	e .				0.53	
R _{thCH}	thermal resistance case to heatsi				0.20		K/W
	total power dissipation		$T_c = 25^{\circ}C$		0.20	180	Ŵ
	max. forward surge current	t = 10 ms; (50 Hz), sine	$T_{c} = 23^{\circ} C$ $T_{v,i} = 45^{\circ} C$			1.15	k/
I _{TSM}	max. lotward surge current	t = 8,3 ms; (60 Hz), sine	$V_{\rm R} = 0 V$			1.13	k/
							N/
		t = 10 ms; (50 Hz), sine	$T_{vJ} = 125 ^{\circ}C$			980	
		t = 8,3 ms; (60 Hz), sine	$V_{\rm R} = 0 V$			1.06	k/
l²t	value for fusing	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			6.62	ł
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$			6.40	
		t = 10 ms; (50 Hz), sine	$T_{vJ} = 125^{\circ}C$			4.80	
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$			4.63	kA ²
C	junction capacitance	$V_{R} = 400 V f = 1 MHz$	$T_{VJ} = 25^{\circ}C$		54		pl
P _{GM}	max. gate power dissipation	t _P = 30 μs	$T_c = 125^{\circ}C$			10	۷
		t _P = 300 μs				5	٧
P _{GAV}	average gate power dissipation					0.5	٧
(di/dt) _{cr}	critical rate of rise of current	T _{vJ} = 125 °C; f = 50 Hz re	epetitive, $I_{T} = 150 \text{ A}$			150	A/μ
		t_{P} = 200 µs; di _G /dt = 0.45 A/µs; -					
		$I_{G} = 0.45 \text{ A}; V = \frac{2}{3} V_{DRM}$ no	on-repet., $I_{\tau} = 49 \text{ A}$			500	A/μ
(dv/dt) _{cr}	critical rate of rise of voltage	$V = \frac{2}{3} V_{DBM}$	T _{v.i} = 125°C			1000	V/μ
τ γο.	-	R _{GK} = ∞; method 1 (linear volta	ge rise)				
V _{gt}	gate trigger voltage	$\frac{V_{\rm D}}{V_{\rm D}} = 6 \text{ V}$	$T_{vJ} = 25^{\circ}C$			1.5	١
- 01			$T_{yJ} = -40^{\circ}C$			1.6	١
I _{GT}	gate trigger current	$V_{D} = 6 V$	$T_{vJ} = 25^{\circ}C$			100	m/
•GT	gate ingger our ent	v _D = 0 v	$T_{VJ} = -40^{\circ}C$			200	1
V	gate non-trigger voltage	$V_{\rm D} = \frac{2}{3} V_{\rm DBM}$	$T_{VJ} = -40^{\circ} \text{C}$ $T_{VJ} = 125^{\circ} \text{C}$				m/ ۱
V _{gd}		$\mathbf{v}_{\mathrm{D}} = 73 \mathbf{v}_{\mathrm{DRM}}$	$1_{VJ} = 125 \text{ G}$			0.2	
I _{GD}	gate non-trigger current		T 0500			10	m/
IL	latching current	$t_p = 10 \ \mu s$ $I_G = 0.45 \ A; \ di_G / dt = 0.45 \ A / \mu s$	$T_{vJ} = 25 ^{\circ}\text{C}$			450	m/
I _H	holding current	$V_{\rm D} = 6 \text{ V} \text{R}_{\rm GK} = \infty$	$T_{vJ} = 25 ^{\circ}C$			200	m/
t _{gd}	gate controlled delay time	$V_{\rm D} = \frac{1}{2} V_{\rm DBM}$	$T_{\rm VJ} = 25 ^{\circ}{\rm C}$			2	μ
3-		$I_{\rm G} = 0.45 \text{A}; \text{di}_{\rm G}/\text{dt} = 0.45 \text{A}/\mu\text{s}$. F*
t _q	turn-off time	$V_{\rm R} = 100 \text{ V}; \ \text{I}_{\rm T} = 120 \text{ A}; \text{V} = \frac{3}{2}$			150		μ
۰q	······································	$v_{\rm H} = 100 v, v_{\rm T} = 120 \Lambda, v = 7$	- DRM IVJ - IOO O		150		μ

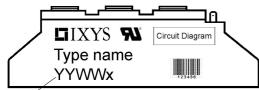
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MCD44-12io8B

Package TO-240AA			Ratings					
Symbol	Definition	Conditions			min.	typ.	max.	Unit
	RMS current	per terminal					200	Α
T _{vj}	virtual junction temperature				-40		125	°C
T _{op}	operation temperature				-40		100	°C
T _{stg}	storage temperature				-40		125	°C
Weight						81		g
M _D	mounting torque				2.5		4	Nm
M _T	terminal torque				2.5		4	Nm
d _{Spp/App}	creenade distance on surfac	e striking distance through air	terminal to terminal	13.0	9.7			mm
d _{Spb/Apb}	creepage uistance on sunac	e Striking distance thiough an	terminal to backside	16.0	16.0			mm
V	isolation voltage	t = 1 second	50/60 Hz, RMS; liso∟ ≤ 1 mA		3600			V
		t = 1 minute			3000			V



Date Code

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MCD44-12io8B	MCD44-12io8B	Box	36	457639

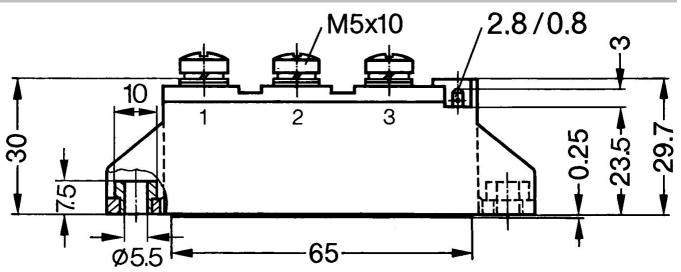
Similar Part	Package	Voltage class
MCMA50PD1200TB	TO-240AA-1B	1200
MCMA65PD1200TB	TO-240AA-1B	1200

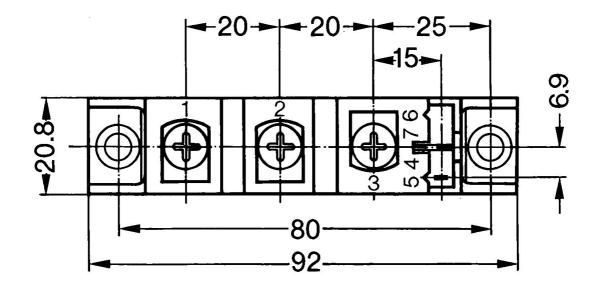
Equivalent Circuits for Simulation			* on die level	T _{vj} = 125 °C
	⊢R₀−	Thyristor		
V _{0 max}	threshold voltage	0.85		V
$\mathbf{R}_{0 \max}$	slope resistance *	4.1		mΩ

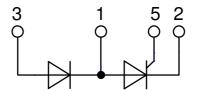
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Outlines TO-240AA







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sin

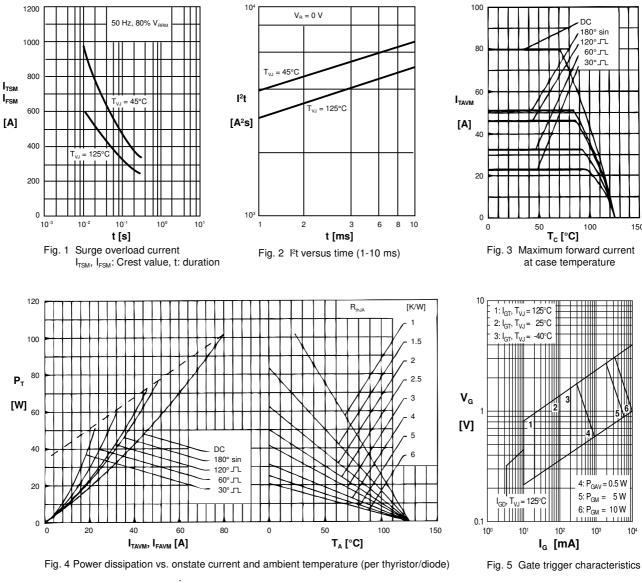
150

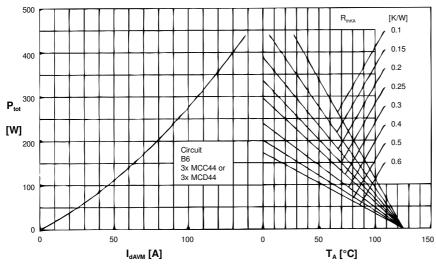
= 0.5 W

1.1.111

10

Thyristor





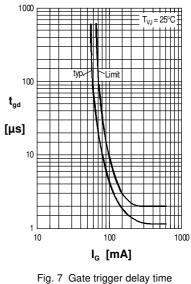
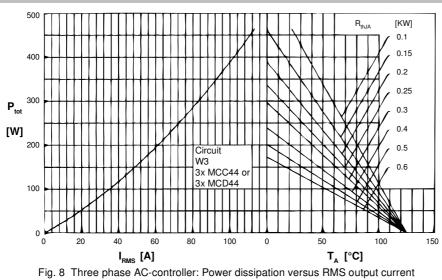


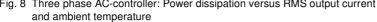
Fig. 6 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature

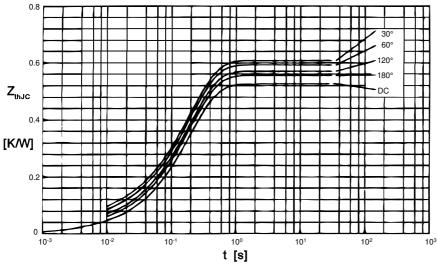
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Rectifier







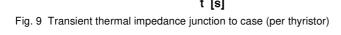
liiju					
	d R _u	_{,JC} [K/W]			
	DC	0.53			
	180°	0.55			
	120°	0.58			
	60°	0.60			
	30°	0.62			
Constants for Z_{thJC} calculation:					
i F	R _{thi} [K/W] t _i [s]			
1	0.015	0.0035			
2	0.026	0.0200			

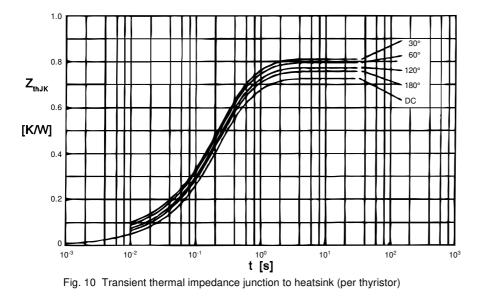
0.1950

3

0.489

 $\mathbf{R}_{_{thJC}}$ for various conduction angles d:





${\sf R}_{{}_{thJK}}$ for various conduction angles d:						
	d R _u	_{JK} [K/W]				
	DC	0.73				
	180°	0.75				
	120°	0.78				
	60°	0.80				
	30°	0.82				
Со	Constants for Z_{thuk} calculation:					
i	R _{thi} [K/W] t _i [s]				
1	0.015	0.0035				
2	0.026	0.0200				
3	0.489	0.0195				
4	0.200	0.6800				

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